

| L Number | Hits | Search Text | DB | Time stamp |
|----------|------|---|---|------------------|
| 1 | 3877 | ((257/664) or (257/700) or (257/728) or (438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS. | USPAT; US-PGPUB | 2004/01/08 20:15 |
| 2 | 29 | ((257/664) or (257/700) or (257/728) or (438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and (input output impedance) near15 (match matching) and (power adj transistor high adj voltage near2 transistor power adj device) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/08 20:18 |
| 3 | 126 | (input output impedance) near15 (match matching) and (power adj transistor high adj voltage near2 transistor power adj device) | EPO; JPO; DERWENT; IBM_TDB | 2004/01/08 20:19 |
| - | 1630 | power adj transistor.ti,ab. and amplifier.ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/01/08 18:04 |
| - | 222 | power adj transistor.ti. and amplifier.ti. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 08:48 |
| - | 23 | power adj transistor.ti. and amplifier.ti. and (rf or radio adj frequency).ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:05 |
| - | 126 | power adj transistor.ti. and (rf or radio adj frequency).ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:07 |
| - | 87 | power adj transistor.ti. and (rf or radio adj frequency).ti. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:30 |
| - | 220 | internal adj matching | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:31 |
| - | 48 | internal adj matching with transistor.ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:34 |
| - | 0 | (internal adj matching with transistor.ti,ab.) and ldmos | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:35 |
| - | 0 | (internal adj matching with transistor.ti,ab.) and ldmosfet | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:35 |
| - | 0 | (internal adj matching with transistor.ti,ab.) and mosfet | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:35 |
| - | 12 | (internal adj matching with transistor.ti,ab.) and field adj effect adj transistor | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 10:35 |

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|---|----|--|---|------------------|
| - | 0 | JP-2001024148 JP-05218102 JP-04321308 JP-01283951 JP-02005459 JP-01199436 JP-63086904 JP-55091148 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:12 |
| - | 14 | JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:13 |
| - | 10 | ((("5371405") or ("6281756") or ("5576661") or ("5206608"))).PN. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:14 |
| - | 4 | EP-680141\$-\$.did. JP-01050602\$-\$.did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:15 |
| - | 0 | ((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608")) or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor and input adj matching and lead and wir\$3 and impedance and (die or dice or chip) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:17 |
| - | 0 | ((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608")) or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor and input adj matching and lead and wir\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:17 |
| - | 8 | ((JP-05218102\$-\$.did. JP-04321308\$-\$.did. JP-01283951\$-\$.did. JP-02005459\$-\$.did. JP-01199436\$-\$.did. JP-63086904\$-\$.did. JP-55091148\$-\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608")) or ("5206608"))).PN.) or (EP-680141\$-\$.did. JP-01050602\$-\$.did.) and substrate and transistor | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:17 |

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|---|------|--|---|------------------|
| - | 8 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:17 |
| - | 2 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:18 |
| - | 2 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 12:18 |
| - | 2 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1 and wir\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 13:41 |
| - | 1 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and substrate and transistor and match\$3 and lead\$1 and wir\$3 and impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 13:43 |
| - | 4393 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and (wir\$3 with impedance) (wir\$3 with impedance).ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 13:43 |
| - | 207 | ((JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (((("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.)) and (wir\$3 with impedance) (wir\$3 with impedance).ti,ab. and 257/\$6.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 13:44 |

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| - | 13 | (bonding adj2 wir\$3 near5 impedance).ti,ab. and 257/\$6.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:39 |
| - | 3 | 5371405.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:40 |
| - | 2 | 6281756.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:42 |
| - | 545 | 257/664 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:43 |
| - | 27 | (JP-05218102\$-\$\$.did. JP-04321308\$-\$\$.did. JP-01283951\$-\$\$.did. JP-02005459\$-\$\$.did. JP-01199436\$-\$\$.did. JP-63086904\$-\$\$.did. JP-55091148\$-\$\$.did.) or (("5371405") or ("6281756") or ("5576661") or ("5206608") or ("5206608")).PN.) or (EP-680141\$-\$\$.did. JP-01050602\$-\$\$.did.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:44 |
| - | 0 | jp-404048756\$-\$\$.did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:45 |
| - | 2 | jp-04048756\$-\$\$.did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:48 |
| - | 1768 | 257/700 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:48 |
| - | 742 | 257/728 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:48 |
| - | 16 | (257/664 or 257/700 or 257/728) and wir\$3 and substrate and power adj transistor and matching and impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/10 16:50 |
| - | 212 | trench same gate same high adj voltage | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/11 07:57 |
| - | 46 | trench same gate same high adj voltage and field adj effect adj transistor and 257/\$6.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/11 07:58 |
| - | 6 | (trench.ti,ab. same gate same high adj voltage) and field adj effect adj transistor and 257/\$6.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/01/11 07:59 |

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| - | 2937 | 257/664 or 257/700 or 257/728 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 15:50 |
| - | 33 | (257/664 or 257/700 or 257/728) and impedance near12 (tailor or tailored or adjust or adjustment) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 15:52 |
| - | 8 | (257/664 or 257/700 or 257/728) and impedance near12 (tailor or tailored or adjust or adjustment) and (length or number) near12 wire | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 16:16 |
| - | 325 | impedance near12 (tailor or tailored or adjust or adjustment) and (length or number) near12 wire | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 16:17 |
| - | 227 | impedance near6 (tailor or tailored or adjust or adjustment) and (length or number) near6 wire | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 16:18 |
| - | 11 | impedance near4 (tailor or tailored or adjust or adjustment) and (length or number) near4 wire and (variance or rms or root-mean-square or root adj mean adj square) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/06/30 16:19 |
| - | 2 | ("5371405").PN. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/10/02 09:33 |
| - | 2 | ("6281756").PN. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/10/02 09:38 |
| - | 0 | ("jp-4048756").PN. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/10/02 09:38 |
| - | 0 | jp-04048756 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/10/02 09:38 |
| - | 2 | jp-04048756\$-\$.did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/10/02 09:38 |
| - | 1135 | impedance near6 (match or matching or matched) near6 (wire or wiring) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 17:10 |
| - | 488 | impedance adj matching near6 (wire or wiring) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 17:10 |
| - | 47 | impedance adj matching near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 19:45 |

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| - | 0 | trimmable near2 (bonding or bond) near2 (wire or wiring) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 19:46 |
| - | 5 | trimmable near12 (bonding or bond) near12 (wire or wiring) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 19:58 |
| - | 8 | trimmable adj (resistance or resistor) near3 laser and (257/\$6.ccls. or 438/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:08 |
| - | 0 | trimmable adj (resistance or resistor) near6 laser near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:04 |
| - | 5 | trimmable adj (resistance or resistor) near6 (wire or wiring) and (257/\$6.ccls. or 438/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:04 |
| - | 20 | trimmable adj (resistance or resistor) near3 laser.ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:19 |
| - | 0 | trimmable adj (resistance or resistor) near3 wire.ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:19 |
| - | 0 | trimmable adj wire.ti,ab. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/12 20:19 |
| - | 8365 | (trimmablele adj resistor-switch or rs) near12 (wire or wiring) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/13 08:05 |
| - | 92 | (trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/13 08:11 |
| - | 0 | (trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) near12 impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/13 08:11 |
| - | 27 | (trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) and (438/\$6.ccls. or 257/\$6.ccls. or 324/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2002/11/13 08:33 |
| - | 287 | (secure or securing) near3 (die or chip) near3 substrate | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:00 |
| - | 2 | (secure or securing) near3 (die or chip) near3 substrate and (test or testing or measure or measuring) near3 performance adj characteristic | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:02 |

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| - | 2 | (secure or securing) near3 (die or chip) near3 substrate and (test or testing or measure or measuring or determine or determining) near3 performance adj characteristic | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:09 |
| - | 8 | impedance near3 adjust same length near3 wire | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:09 |
| - | 37 | (resistance or impedance) near3 (adjust or adjustment) same (length near3 (wire or wiring)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:10 |
| - | 0 | (resistance or impedance) near3 (adjust or adjustment) near12 (length near3 (wire or wiring)) and (die or chip) near12 substrate | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:12 |
| - | 1 | (resistance or impedance) near3 (adjust or adjustment) near12 (length near3 (wire or wiring)) and (die or chip) same substrate | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 15:12 |
| - | 27 | (US-6177801-\$ or US-6084946-\$ or US-6060778-\$ or US-5978449-\$ or US-5864602-\$ or US-5862040-\$ or US-5578931-\$ or US-5528156-\$ or US-5633595-\$ or US-5600240-\$ or US-6389109-\$ or US-5592099-\$ or US-5589780-\$ or US-6417672-\$ or US-6385297-\$ or US-6225811-\$ or US-4320338-\$ or US-3660249-\$ or US-5485093-\$ or US-5250908-\$ or US-4495465-\$ or US-6456088-\$).did. or (US-20020105336-\$).did. or (EP-103971-\$).did. or (JP-01282476-\$ or JP-62272550-\$ or JP-04102345-\$).did. | USPAT; US-PGPUB; EPO; JPO | 2003/01/23 15:44 |
| - | 62 | (trimmable adj resistor-switch or rs) near12 (wire or wiring) near12 (testing or test) not (438/\$6.ccls. or 257/\$6.ccls. or 324/\$6.ccls.) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 16:36 |
| - | 4168 | ((438/10) or (438/11) or (438/13) or (438/17) or (438/18)).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 16:37 |
| - | 2 | ((((438/10) or (438/11) or (438/13) or (438/17) or (438/18)).CCLS.) and impedance near3 match\$3 and power adj2 (transistor or FET or MOSFET or NMOSFET or CMOSFET or PMOSFET or VMOSFET or UMOSFET or DMOSFET or field adj effect adj transistor) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 16:39 |
| - | 0 | (wire or wiring) near6 (varied or varying) near6 number near12 impedance and power.ti,ab. and (die or chip) and substrate | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/23 19:05 |
| - | 28 | power adj2 (semiconductor or transistor).ti,ab. and impedance near12 (adjust or adjusting or match or matching) near12 (wire or wiring or lead or leads) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 09:45 |

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| - | 15 | (US-5973567-\$ or US-5880517-\$ or US-5696466-\$ or US-5552636-\$ or US-5446959-\$ or US-5023189-\$ or US-4042952-\$ or US-6501159-\$ or US-6177834-\$).did. or (US-20020134993-\$ or US-20010038310-\$ or US-20010004115-\$).did. or (JP-11238851-\$).did. or (EP-1237189-\$ or US-6177834-\$).did. | USPAT; US-PGPUB; JPO; DERWENT | 2003/01/24 08:45 |
| - | 437 | interconnect\$3.ti,ab. and semiconductor.ti,ab. and line adj width | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 09:47 |
| - | 34 | (interconnect\$3.ti,ab. and semiconductor.ti,ab. and line adj width) and impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:27 |
| - | 953 | (438/14).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:27 |
| - | 12 | ((438/14).CCLS.) and impedance near12 (wire or wiring or interconnect\$3) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:38 |
| - | 0 | impedance near3 matching adj circuit near12 (number near3 wires) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:41 |
| - | 382 | (324/719).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:45 |
| - | 120 | impedance near6 wires near6 number | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:46 |
| - | 0 | ((324/719).CCLS.) and (impedance near6 wires near6 number) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:46 |
| - | 6 | adjust\$3 near6 impedance near6 wires near6 number | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 10:47 |
| - | 7 | adjust\$4 near6 impedance near6 wires near6 number | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 11:48 |
| - | 2 | (("5023189") or ("6331804")).PN. | USPAT | 2003/01/24 11:49 |
| - | 2 | (US-6331804-\$ or US-5023189-\$).did. | USPAT | 2003/01/24 11:49 |
| - | 18 | jp-0600615\$-\$).did. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/01/24 11:50 |
| - | 8 | jp-0600615\$-\$).did. | JPO | 2003/01/24 11:50 |
| - | 5 | 813604.ap. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/07 15:02 |

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|---|-------|---|---|------------------|
| - | 392 | input near5 transistor near5 (match matching) near5 impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/07 15:20 |
| - | 13 | (US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did. | USPAT; US-PGPUB | 2003/07/07 15:20 |
| - | 13 | ((US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did.) and input near5 transistor near5 (match matching) near5 impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/07 15:23 |
| - | 13 | ((US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5387888-\$ or US-5371405-\$ or US-5696466-\$ or US-6348718-\$ or US-6501159-\$ or US-6479846-\$ or US-6455925-\$ or US-6331804-\$).did. or (US-20010004115-\$ or US-20020134993-\$).did.) and input near5 transistor near5 (match matching) near5 impedance | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/07 17:05 |
| - | 48 | impedance and matching (US-6177834-\$ or US-5880517-\$ or US-5696466-\$ or US-5539254-\$ or US-4042952-\$ or US-5387888-\$ or US-5492842-\$ or US-5563447-\$ or US-5519253-\$ or US-5444295-\$ or US-6501159-\$ or US-5973567-\$ or US-5552636-\$ or US-5446959-\$ or US-6331804-\$ or US-5982793-\$ or US-6479846-\$ or US-6455925-\$ or US-6348718-\$ or US-4200880-\$ or US-4004256-\$ or US-3942186-\$ or US-5371405-\$ or US-5023189-\$ or US-6281756-\$ or US-5576661-\$).did. or (US-5206608-\$).did. or (US-20020134993-\$ or US-20010038310-\$ or US-20010004115-\$).did. or (EP-680141-\$ or US-5206608-\$).did. or (JP-04218949-\$ or JP-07270443-\$ or JP-03114251-\$ or JP-05002316-\$ or JP-11238851-\$ or JP-06006150-\$ or JP-04321308-\$ or JP-02005459-\$ or JP-01199436-\$ or JP-01283951-\$ or JP-63086904-\$ or JP-55091148-\$ or JP-05218102-\$ or JP-2001024148-\$).did. or (EP-1237189-\$ or US-6177834-\$ or JP-01050602-\$).did. | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2003/07/08 07:55 |
| - | 5156 | ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 07:58 |
| - | 7 | ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and (rf radio-frequency radio adj frequency) and impedance near12 match\$3 and wir\$3 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:07 |
| - | 10407 | impedance adj matching.ti,ab,clm. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:07 |

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|---|------|--|---|------------------|
| - | 263 | substrate and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:09 |
| - | 5 | substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ((step steps) near12 order) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:12 |
| - | 121 | substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:54 |
| - | 0 | substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ("in" adj situ) near6 (test testing measuring measurement) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:55 |
| - | 0 | substrate and transistor and (die or chip) and (wire wiring wires)and impedance adj matching.ti,ab,clm. and ("in" adj situ) near16 (test testing measuring measurement) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:55 |
| - | 0 | ("in" adj situ) near16 (test testing measuring measurement) same impedance adj matching | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/08 08:55 |
| - | 5161 | ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/10 08:02 |
| - | 18 | ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and impedance near20 (match matching) and (wire wiring wires) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/10 08:05 |
| - | 3 | ((438/10) or (438/11) or (438/13) or (438/14) or (438/17) or (438/18)).CCLS.) and impedance near20 (match matching) and (wire wiring wires) and transistor near20 (chip die) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2003/07/10 08:05 |